

# TISP3xxxT3BJ Overvoltage Protector Series

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## Absolute Maximum Ratings, $T_A = 25^\circ\text{C}$ (Unless Otherwise Noted)

Rating	Symbol	Value	Unit
Repetitive peak off-state voltage, (terminals 1-2 and 3-2)	'3070	$\pm 58$	V
	'3080	$\pm 65$	
	'3095	$\pm 75$	
	'3115	$\pm 90$	
	'3125	$\pm 100$	
	'3145	$\pm 120$	
	'3165	$\pm 135$	
	'3180	$\pm 145$	
	'3200	$\pm 155$	
	'3219	$\pm 180$	
	'3250	$\pm 190$	
	'3290	$\pm 220$	
	'3350	$\pm 275$	
	'3395	$\pm 320$	
Non-repetitive peak on-state pulse current (see Notes 1 and 2)	$I_{PPSM}$	2x250	A
2/10 (Telcordia GR-1089-CORE, 2/10 voltage wave shape)		2x250	
8/20 (IEC 61000-4-5, combination wave generator, 1.2/50 voltage wave shape)		2x150	
10/160 (TIA/EIA-IS-968 (replaces FCC Part 68), 10/160 $\mu\text{s}$ voltage wave shape)		2x120	
5/310 (ITU-T K.44, 10/700 $\mu\text{s}$ voltage wave shape used in K.20/.45/.21)		2x120	
5/320 (TIA/EIA-IS-968 (replaces FCC Part 68), 9/720 $\mu\text{s}$ voltage wave shape)		2x100	
10/560 (TIA/EIA-IS-968 (replaces FCC Part 68), 10/560 $\mu\text{s}$ voltage wave shape)		2x80	
Non-repetitive peak on-state current (see Notes 1 and 2)	$I_{TSM}$	2x25	A
50 Hz, 1 cycle		2x30	
60 Hz, 1 cycle		2x1.2	
1000 s 50 Hz/60 Hz a.c.			
Initial rate of rise of on-state current, Linear current ramp, Maximum ramp value < 50 A	$di_T/dt$	500	A/ $\mu\text{s}$
Junction temperature	$T_J$	-40 to +150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-65 to +150	$^\circ\text{C}$

NOTES: 1. Initially, the device must be in thermal equilibrium with  $T_J = 25^\circ\text{C}$ .

2. These non-repetitive rated currents are peak values of either polarity. The rated current values are applied to the terminals 1 and 3 simultaneously (in this case the terminal 2 return current will be the sum of the currents applied to the terminals 1 and 3). The surge may be repeated after the device returns to its initial conditions.

## Recommended Operating Conditions

Component	Min	Typ	Max	Unit
Series resistor for GR-1089-CORE first-level surge survival	5			$\Omega$
Series resistor for ITU-T recommendation K.20/.45/.21 (coordination with 400 V GDT at 4 kV)	6.4			
R1, R2 Series resistor for TIA/EIA-IS-968 (replaces FCC Part 68) 9/720 survival	0			
Series resistor for TIA/EIA-IS-968 (replaces FCC Part 68) 10/560 survival	0			
Series resistor for TIA/EIA-IS-968 (replaces FCC Part 68) 10/160 survival	2.5			

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Electrical Characteristics for the 1 and 2 or the 3 and 2 Terminals,  $T_A = 25\text{ }^{\circ}\text{C}$

Parameter	Test Conditions	Min	Typ	Max	Unit
$I_{\text{DRM}}$ Repetitive peak off-state current	$V_D = V_{\text{DRM}}$ $T_A = 25\text{ }^{\circ}\text{C}$ $T_A = 85\text{ }^{\circ}\text{C}$			$\pm 5$ $\pm 10$	$\mu\text{A}$
$V_{(\text{BO})}$ AC breakover voltage	$dv/dt = \pm 250\text{ V/ms}$ , $R_{\text{SOURCE}} = 300\text{ }\Omega$			$\pm 70$ $\pm 80$ $\pm 95$ $\pm 115$ $\pm 125$ $\pm 145$ $\pm 165$ $\pm 180$ $\pm 200$ $\pm 219$ $\pm 250$ $\pm 290$ $\pm 350$ $\pm 395$	V
$V_{(\text{BO})}$ Ramp breakover voltage	$dv/dt = \pm 1000\text{ V}/\mu\text{s}$ , Linear voltage ramp, Maximum ramp value = $\pm 500\text{ V}$ $di/dt = \pm 20\text{ A}/\mu\text{s}$ , Linear current ramp, Maximum ramp value = $\pm 10\text{ A}$			$\pm 81$ $\pm 91$ $\pm 107$ $\pm 128$ $\pm 138$ $\pm 159$ $\pm 179$ $\pm 195$ $\pm 215$ $\pm 234$ $\pm 265$ $\pm 304$ $\pm 361$ $\pm 403$	V
$I_{(\text{BO})}$ Breakover current	$dv/dt = \pm 250\text{ V/ms}$ , $R_{\text{SOURCE}} = 300\text{ }\Omega$			$\pm 800$	mA
$I_H$ Holding current	$I_T = \pm 5\text{ A}$ , $di/dt = \pm 30\text{ mA/ms}$	$\pm 150$			mA
$dv/dt$ Critical rate of rise of off-state voltage	Linear voltage ramp, Maximum ramp value $< 0.85V_{\text{DRM}}$	$\pm 5$			kV/ $\mu\text{s}$
$I_D$ Off-state current	$V_D = \pm 50\text{ V}$ $T_A = 85\text{ }^{\circ}\text{C}$			$\pm 10$	$\mu\text{A}$

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## Electrical Characteristics for the 1 and 2 or the 3 and 2 Terminals, $T_A = 25^\circ\text{C}$ (Continued)

Parameter	Test Conditions	Min	Typ	Max	Unit	
C <sub>off</sub> Off-state capacitance	f = 1 MHz,    Vd = 1 V rms, V <sub>D</sub> = 0,				pF	
			'3070 thru '3095	95		114
			'3115 thru '3219	69		83
	f = 1 MHz,    Vd = 1 V rms, V <sub>D</sub> = -1 V		'3250 thru '3395	51		62
			'3070 thru '3095	90		108
			'3115 thru '3219	63		76
	f = 1 MHz,    Vd = 1 V rms, V <sub>D</sub> = -2 V		'3250 thru '3395	46		55
			'3070 thru '3095	83		100
			'3115 thru '3219	59		70
	f = 1 MHz,    Vd = 1 V rms, V <sub>D</sub> = -50 V		'3250 thru '3395	42		51
			'3070 thru '3095	43		51
			'3115 thru '3219	29		35
	f = 1 MHz,    Vd = 1 V rms, V <sub>D</sub> = -100 V (see Note 3)		'3250 thru '3395	20		24
'3250 thru '3395		16	19			

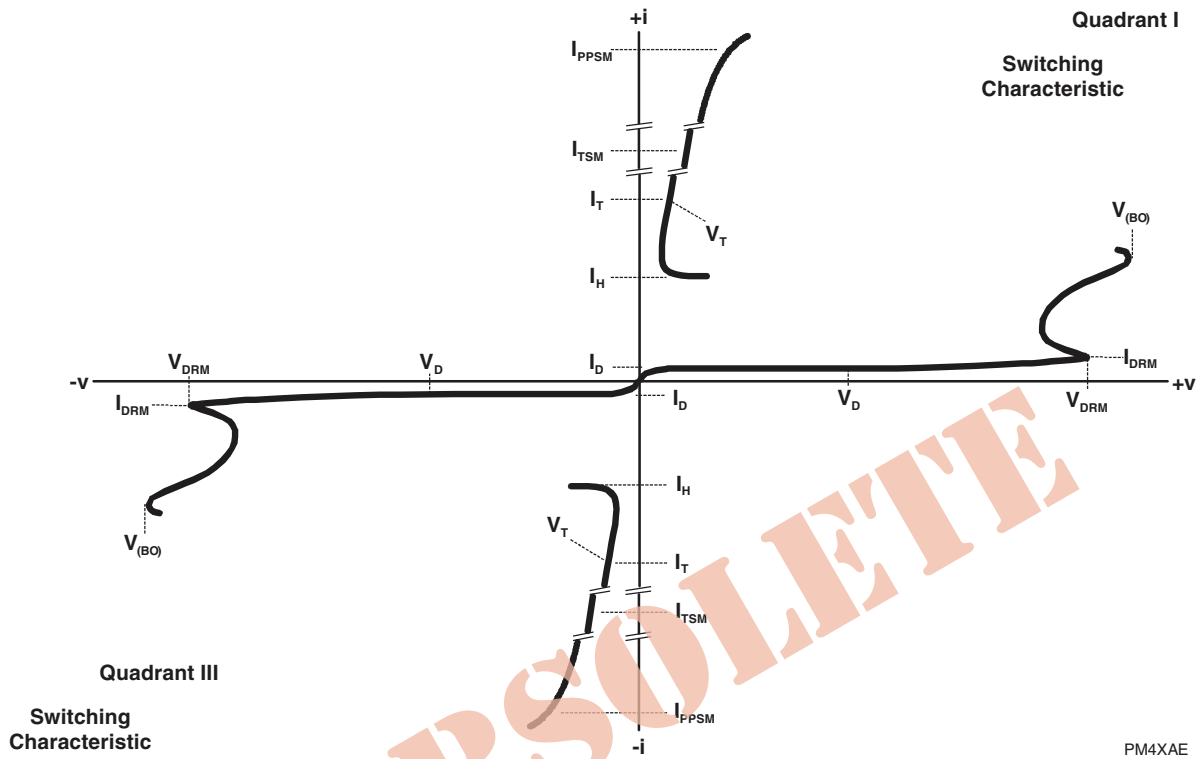
NOTE 3: These capacitance measurements employ a three terminal capacitance bridge incorporating a guard circuit. The unmeasured third terminal is connected to the guard terminal of the bridge.

## Thermal Characteristics

Parameter	Test Conditions	Min	Typ	Max	Unit
$R_{\theta JA}$ Junction to free air thermal resistance	EIA/JESD51-3 PCB, $I_T = I_{TSM(1000)},$ $T_A = 25^\circ\text{C}$ , (see Note 4)			90	$^\circ\text{C/W}$

NOTE 4: EIA/JESD51-2 environment and PCB has standard footprint dimensions connected with 5 A rated printed wiring track widths.

## Parameter Measurement Information



**Figure 1. Voltage-Current Characteristic for Terminal Pairs 1-2 and 3-2**  
**All Measurements are Referenced to Terminal 2**

PM4XAE

## Typical Characteristics

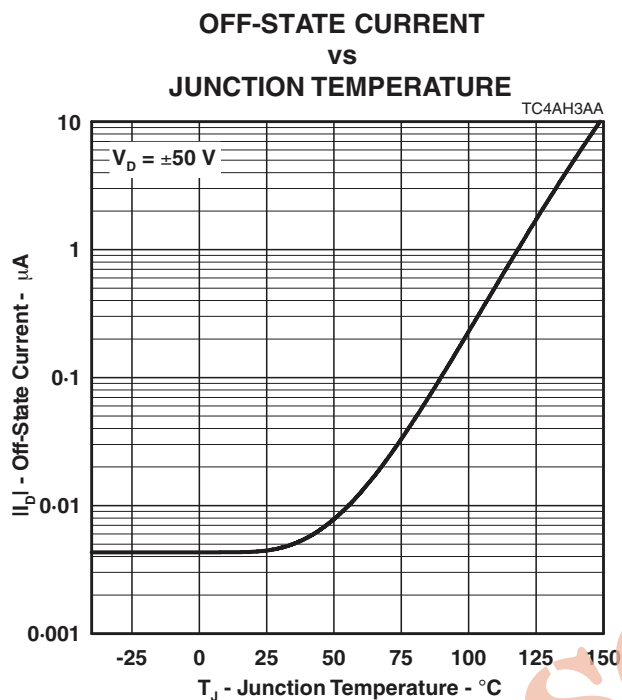


Figure 2.

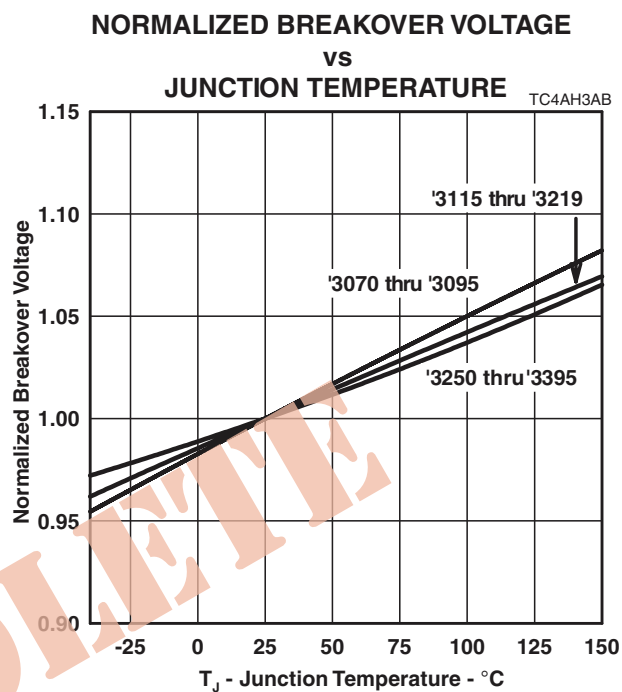


Figure 3.

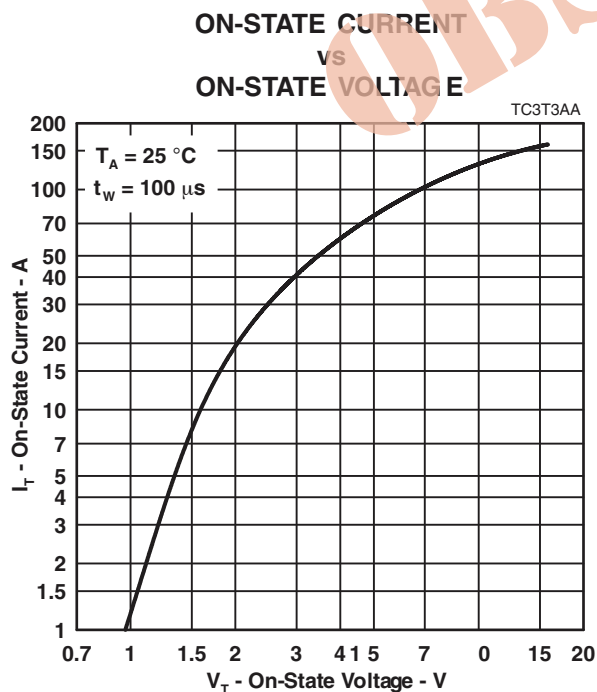


Figure 4.

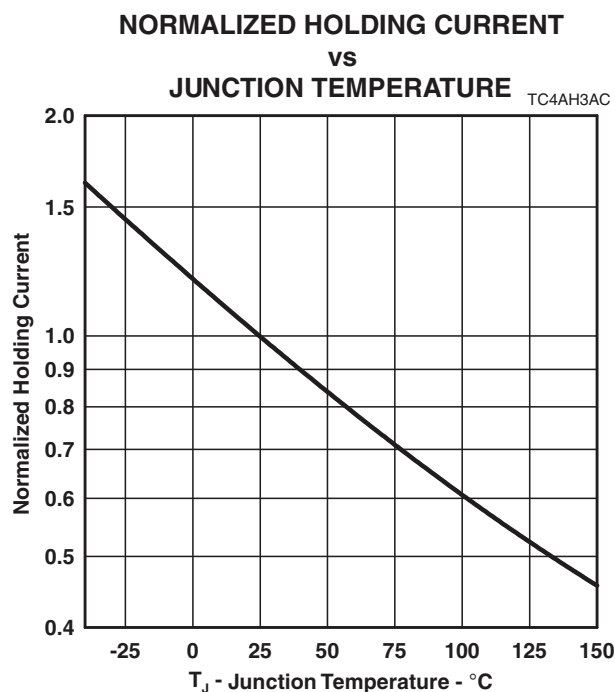


Figure 5.

## Rating and Thermal Information

### NON-REPETITIVE PEAK ON-STATE CURRENT VS CURRENT DURATION

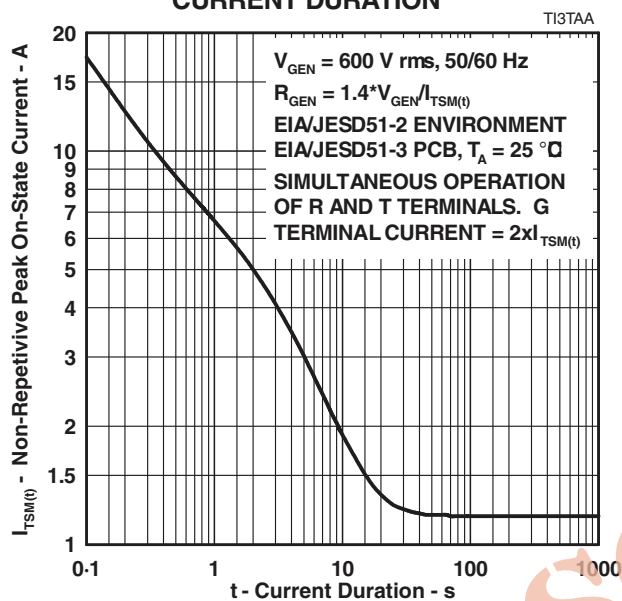


Figure 8.

### $V_{DRM}$ DERATING FACTOR VS MINIMUM AMBIENT TEMPERATURE

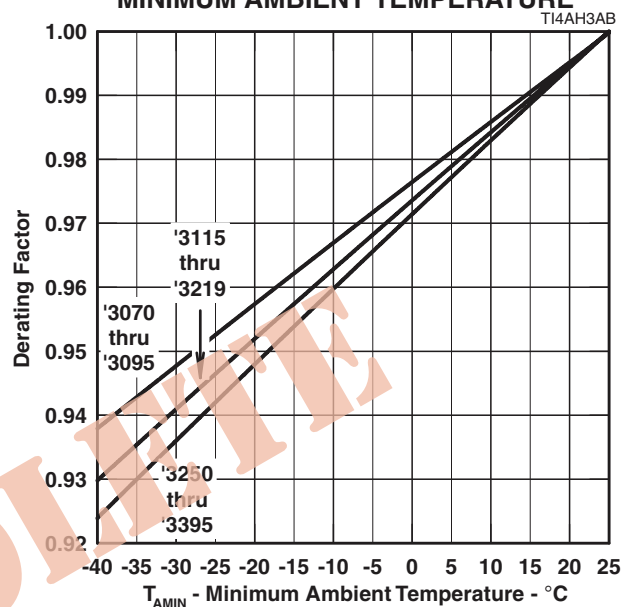


Figure 9.

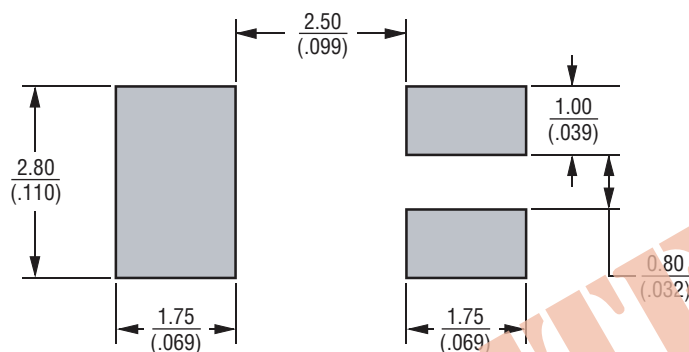
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## MECHANICAL DATA

### Recommended Printed Wiring Land Pattern Dimensions

#### SMB03 Pad Size



DIMENSIONS ARE:  $\frac{\text{MILLIMETERS}}{(\text{INCHES})}$

MD3BJAAA

### Device Symbolization Code

Devices will be coded as below.

Device	Symbolization Code
TISP3070T3	3070T3
TISP3080T3	3080T3
TISP3095T3	3095T3
TISP3115T3	3115T3
TISP3125T3	3125T3
TISP3145T3	3145T3
TISP3165T3	3165T3
TISP3180T3	3180T3
TISP3200T3	3200T3
TISP3219T3	3219T3
TISP3250T3	3250T3
TISP3290T3	3290T3
TISP3350T3	3350T3
TISP3395T3	3395T3

### Carrier Information

For production quantities, the carrier will be embossed tape reel pack. Evaluation quantities may be shipped in bulk pack or embossed tape.

Package	Carrier	Standard Quantity
SMB	Embossed Tape Reel Pack	3000

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Specifications are subject to change without notice.

Customers should verify actual device performance in their specific applications.

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